

WSB5532L

1A Schottky Barrier Diode

[Http://www.sh-willsemi.com](http://www.sh-willsemi.com)

Features

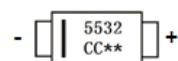
- Low leakage current
- Low forward voltage drop
- SOD-123T package



SOD-123T



Circuit



Marking

Applications

- Switching circuit
- Middle current rectification

Absolute maximum ratings

Parameter	Symbol	Value	Unit
Reverse voltage (repetitive peak)	V_{RRM}	40	V
Reverse voltage (DC)	V_R	40	V
Average rectified forward current (DC)	I_o	1	A
Forward Peak Surge Current ⁽¹⁾	I_{FSM}	50	A
Junction temperature	T_J	-55 ~ 150	°C
Operating temperature	T_{opr}	-55 ~ 150	°C
Storage temperature	T_{stg}	-55 ~ 150	°C

Electronics characteristics ($T_A=25^\circ C$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward voltage ⁽²⁾	V_F	$I_F=1A$		0.41	0.46	V
		$I_F=2A$		0.47	0.53	V
Reverse current	I_R	$V_R=40V$			0.1	mA
Junction capacitance	C_J	$V_R=4V, F=1MHz$		156		pF
Thermal resistance ⁽³⁾	$R_{\theta(J-A)}$	Junction to Ambient		118		K/W

Order Informations

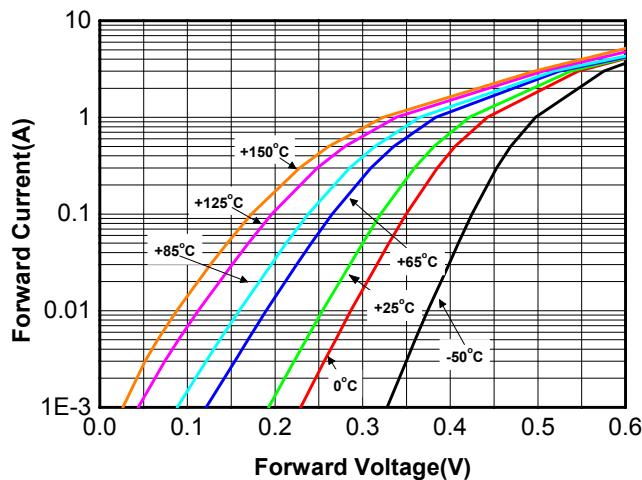
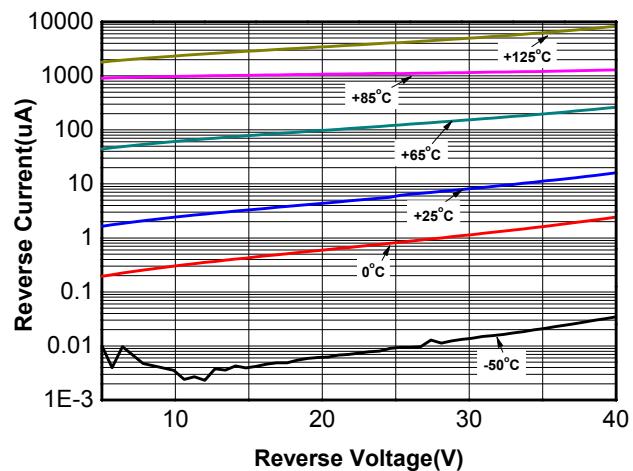
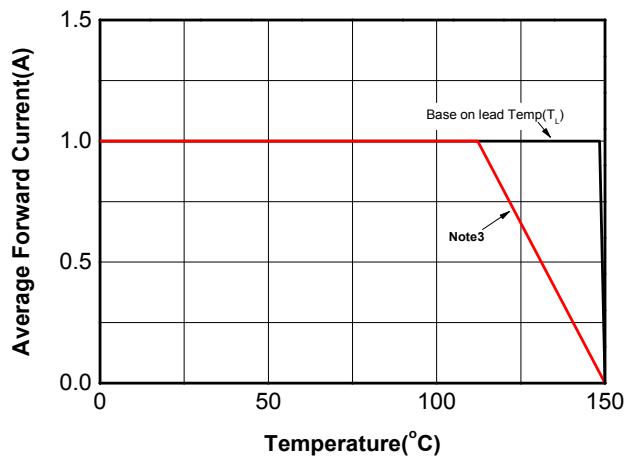
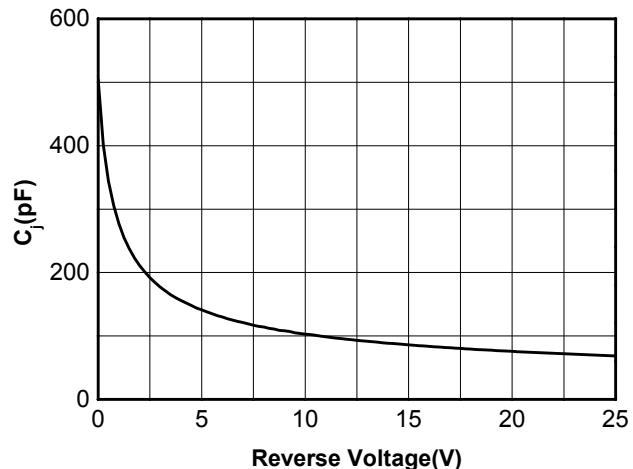
Device	Package	Marking	Shipping
WSB5532L-2/TR	SOD-123T	CC** ⁽⁴⁾	10K/Reel&Tape

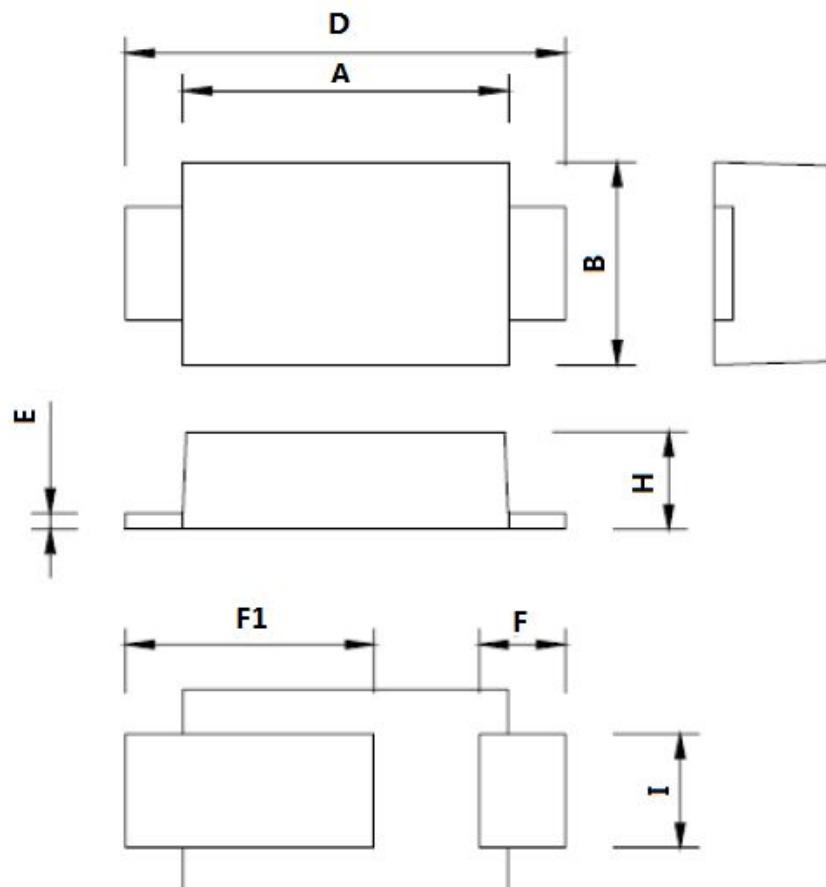
Note1: Pulse width=8.3ms, single pulse;

Note2: Single Pulse, test $T_p=380\mu s$;

Note3: Polymide PCB, 2oz. Copper. Cathode pad dimensions 2.4mm x 1.4mm. Anode pad dimensions 1.0mm x 1.4mm ;

Note4: ** =Month code (AA~Zz); CC =Special code;

Typical characteristics (Ta=25°C, unless otherwise noted)

Fig.1 Forward voltage vs. Forward current

Fig.2 Reverse current vs. Reverse voltage

Fig.3 Maximum Forward Current Derating Curve

Fig.4 Junction capacitance vs. Reverse voltage

Package outline dimensions
SOD-123T


Symbol	Dimensions In Millimeters	
	Min.	Max.
A	2.60	3.00
B	1.70	2.10
D	3.45	3.95
E	0.10	0.30
F	0.30	0.90
F1	1.80	2.40
H	1.05	1.35
I	0.85	1.15